SILICON HIGH VOLTAGE PNP TRANSISTORS



www.centralsemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR MPSA92 and MPSA93 are silicon PNP transistors designed for high voltage applications.

MARKING: FULL PART NUMBER



MAXIMUM RATINGS: (T _A =25°C unless otherwise noted)						
		SYMBOL	MPSA92	N	IPSA93	UNITS
Collector-Base	e Voltage	V_{CBO}	300		200	V
Collector-Emit	ter Voltage	V_{CEO}	300		200	V
Emitter-Base \	Voltage	V_{EBO}		5.0		V
Continuous Co	ollector Current	IC		500		mA
Power Dissipa	ition	P_{D}		625		mW
Power Dissipa	ition (T _C =25°C)	P_{D}		1.5		W
Operating and	Storage Junction Temperature	T _J , T _{stg}	-65	to +15	50	°C
Thermal Resis	stance	$\Theta_{\sf JA}$		200		°C/W
Thermal Resis	stance	$_{\Theta}$ JC		83.3		°C/W
ELECTRICAL	CHARACTERISTICS: (T _A =25°C)	MPS	A92	MPS	6A93	
SYMBOL	TEST CONDITIONS	MIN	MAX	MIN	MAX	UNITS
I _{CBO}	V _{CB} =200V	-	250	-	-	nA
ICEO	V _{CE} =160V	-	-	-	250	nA

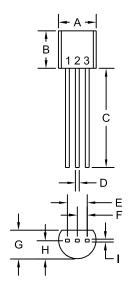
SYMBOL	TEST CONDITIONS	MIN	MAX	MIN	MAX	UNITS
ICBO	V _{CB} =200V	-	250	-	-	nA
I _{CEO}	V _{CE} =160V	-	-	-	250	nA
I _{EBO}	V _{EB} =3.0V	-	100	-	100	nA
BV _{CBO}	I _C =100μA	300	-	200	-	V
BVCEO	I _C =1.0mA	300	-	200	-	V
BVEBO	I _E =100μA	5.0	-	5.0	-	V
VCE(SAT)	I _C =20mA, I _B =2.0mA	-	0.5	-	0.4	V
V _{BE(SAT)}	I _C =20mA, I _B =2.0mA	-	0.9	-	0.9	V
h _{FE}	V _{CE} =10V, I _C =1.0mA	25	-	25	-	
hFE	V _{CE} =10V, I _C =10mA	40	-	40	-	
h_{FE}	V _{CE} =10V, I _C =30mA	25	-	25	-	
f_{T}	V_{CE} =20V, I_{C} =10mA, f=100MHz	50	-	50	-	MHz
C_{ob}	V_{CB} =20V, I_E =0, f=1.0MHz	-	6.0	-	8.0	pF

SILICON **HIGH VOLTAGE** PNP TRANSISTORS



TO-92 CASE - MECHANICAL OUTLINE

R1



DIMENSIONS						
	INCHES		MILLIMETERS			
SYMBOL	MIN	MAX	MIN	MAX		
A (DIA)	0.175	0.205	4.45	5.21		
В	0.170	0.210	4.32	5.33		
С	0.500	-	12.70	-		
D	0.016	0.022	0.41	0.56		
Е	0.100		2.54			
F	0.050		1.27			
G	0.125	0.165	3.18	4.19		
Н	0.080	0.105	2.03	2.67		
	0.015		0.38			

TO-92 (REV: R1)

LEAD CODE:

- 1) Emitter
- 2) Base 3) Collector

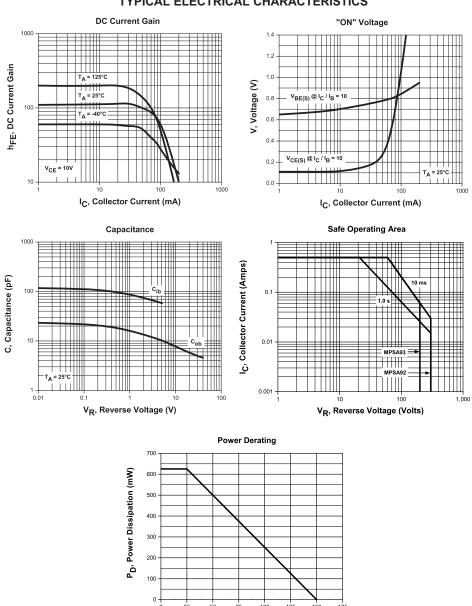
MARKING:

FULL PART NUMBER

SILICON HIGH VOLTAGE PNP TRANSISTORS



TYPICAL ELECTRICAL CHARACTERISTICS



T_A, Ambient Temperature (°C)

R2 (15-December 2014)

SILICON HIGH VOLTAGE PNP TRANSISTORS



SERVICES

- · Bonded Inventory
- · Custom Electrical Screening
- Custom Electrical Characteristic Curves
- SPICE Models
- Custom Packaging
- Package Base Options
- Custom Device Development/Multi Discrete Modules (MDM™)
- · Bare Die Available for Hybrid Applications

LIMITATIONS AND DAMAGES DISCLAIMER: In no event shall Central be liable for any collateral, indirect, punitive, incidental, consequential, or exemplary damages in connection with or arising out of a purchase order or contract or the use of products provided hereunder, regardless of whether Central has been advised of the possibility of such damages. Excluded damages shall include, but not be restricted to: cost of removal or reinstallation, rework, ancillary costs to the procurement of substitute products, loss of profits, loss of savings, loss of use, loss of data, or business interruption. No claim, suit, or action shall be brought against Central more than two (2) years after the related cause of action has occurred.

In no event shall Central's aggregate liability from any warranty, indemnity, or other obligation arising out of or in connection with a purchase order or contract, or any use of any Central product provided hereunder, exceed the total amount paid to Central for the specific products sold under a purchase order or contract with respect to which losses or damages are claimed. The existence of more than one (1) claim against the specific products sold to Buyer under a purchase order or contract shall not enlarge or extend this limit.

Buyer understands and agrees that the foregoing liability limitations are essential elements of a purchase order or contract and that in the absence of such limitations, the material and economic terms of the purchase order or contract would be substantially different.

R2 (15-December 2014)

AMEYA360 Components Supply Platform

Authorized Distribution Brand:

























Website:

Welcome to visit www.ameya360.com

Contact Us:

> Address:

401 Building No.5, JiuGe Business Center, Lane 2301, Yishan Rd Minhang District, Shanghai , China

> Sales:

Direct +86 (21) 6401-6692

Email amall@ameya360.com

QQ 800077892

Skype ameyasales1 ameyasales2

Customer Service :

Email service@ameya360.com

Partnership :

Tel +86 (21) 64016692-8333

Email mkt@ameya360.com